American University of Beirut

Department of Electrical and Computer Engineering EECE 311 – Electronic Circuits Spring 2014 Midterm – March 21, 2014 Open Book – 120 minutes

NAME:	ID Number:

- ✤ All questions are equally graded
- PENALTY is <u>four-to-one</u> (four wrong answers cancel one correct answer, one to three wrong answers have no effect)
- Grading is based on the answers marked on the SCANTRON sheet only.
- ✤ There are 28 questions and 8 pages in this exam.
- Unless otherwise specified, neglect the effect of V_A (channel-length modulation in MOSFETs, or base-width modulation in BJTs)
- Assume $V_{\rm T} = 25$ mV and $V_{\rm BE(ACTIVE)} = 0.7$ V.

1. Find the exact 3-dB frequency (in kHz) for the amplifier with the following transfer function. Assume A = 8.

$$F_H(s) = \frac{1 - \frac{s}{3 \times 10^5}}{\left(1 + \frac{s}{A \times 10^4}\right)}$$

a) 15.8 b) 13.7 c) 8.2 d) 10.0 e) 11.8

2. Find the 3-dB frequency (in kHz) for the amplifier with the following transfer function. Use the most appropriate method to obtain a *quick* answer. Assume A = 2.

$$F_H(s) = \frac{1 - \frac{s}{3 \times 10^6}}{\left(1 + \frac{s}{A \times 10^4}\right) \left(1 + \frac{s}{9 \times 10^5}\right) \left(1 + \frac{s}{4 \times 10^6}\right)}$$

b) 4.8 c) 6.4 d) 8.0 e) 1.6

3. Consider the amplifier gain function shown below. When the input voltage is $v_i(t) = 7 \sin(\omega t) \text{ mV}$ with $\omega = 2\pi \times 3000 \text{ rad/sec}$, the output is $v_o(t) = X \sin(\omega t + \phi) \text{ mV}$. Find X (in mV).

a) <mark>3.2</mark>

$$A(s) = \frac{1000}{\left(1 + \frac{s}{3 \times 10^3}\right)}$$

a) 2123.2 b) 1625.5 c) 1313.2 d) 1100.2 e) 946.2
4. In the previous problem, find ϕ (in degrees).
a) -81.0 b) -79.2 c) -82.2 d) -72.3 e) -76.6

The asymptotic magnitude Bode plot of an amplifier with three poles and no zeros is shown below.



The reference current in the circuit shown below is 60 μ A. Assume $V_{DD} = 2$ V and that $(W/L)_1$ for MOSFET Q_1 is 10, while $(W/L)_2$ for MOSFET Q_2 is 15. For the two MOSFETs, $k'_n = 400 \ \mu$ A/V², and $V_t = 0.5$ V.



6. What is the minimum value of output voltage $V_{\rm O}$ (in V) to maintain proper current source operation? a) 0.200 b) 0.245 c) 0.173 d) 0.155 e) 0.346

a) 0.200 b) 0.245 c) 0.173 d) 0.155 e) 0.346

7. Find the output current I_0 (in μ A) when a resistor $R_S = 2 \text{ k}\Omega$ is inserted between the source of Q_2 and ground (as shown below). All other parameters are unchanged.



8. Assume that after adding the resistor $R_{\rm S} = 2 \text{ k}\Omega$ between source of Q_2 and ground, the reference current was adjusted such that for Q_2 , $r_{o2} = 20 \text{ k}\Omega$ and $g_{m2} = 0.2 \text{ mA/V}$. Find the output resistance (in k Ω) of the current source. a) 42 b) 46 c) 34 d) 38 e) **30**

In the circuit shown below, assume that for the MOSFETS, the small-signal parameters are: $g_{m1} = 4 \text{ mA/V}, g_{m2} = 2 \text{ mA/V}, r_{o1} = 34 \text{ k}\Omega$, and $r_{o2} = 48 \text{ k}\Omega$. The signal and load resistances are $R_{sig} = 5 \text{ k}\Omega$ and $R_{L} = 18 \text{ k}\Omega$. For high-frequency analysis, the MOSFETs have $C_{gs} = 2 \text{ pF}$ and $C_{\rm gd} = 0.6 \, \rm pF.$



9. Find the OCTC resistance seen by a capacitor connected between the output node and ground (in $k\Omega$). 0.3

a) 7.91 b) 8.82	c) <mark>9.45</mark>	d) 9.98	e) 1
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10. Apply Miller's theorem to find the total capacitance (in pF) that appears between the output node and ground.

c) 1.22 a) 1.01 b) 1.62 d) 0.81 e) 0.41

11. Use Miller's approximation to find an estimate of ω_{3dB} , the 3-dB frequency of $|V_o/V_{sig}|$, in Mrad/s. Assume that ω_{3dB} is determined by a single dominant pole at the input. a) 10.89 b) 8.67 d) 7.91 c) 6.45 e) 23.45

12. In the circuit shown below, the opamp is ideal. Assume $R_2 = R_4 = 10 \text{ k}\Omega$, $R_1 = 1 \text{ k}\Omega$, and $R_3 = 1.02 \text{ k}\Omega$. Calculate the Common Mode Rejection Ratio (in dB) of this difference amplifier.



In the circuit shown below, the transistors are biased in the saturation region using two *ideal* current sources: $I_1 = 0.1$ mA, and $I_2 = 2I_1$. The two large capacitors shown are open-circuits at DC, but can be considered as short-circuits for all signal frequencies of interest, and during OCTC calculations. The amplifier comprises two stages. The first stage is built around MOSFET Q_1 , while the second stage is built around MOSFET Q_2 . Assume $R_{sig} = R_L = 2 \text{ k}\Omega$. The two transistors have $k'(W/L) = 1 \text{ mA/V}^2$.



13. The Q_1 stage is a common-... stage, and the Q_2 stage is a common-... stage

a) source, drain
b) gate, source
c) source, source
d) drain, gate
e) gate, drain

14. Find the value of the resistor R (in k Ω) to make the DC voltage at the gate of Q_2 equal to *zero* Volt.

a) 12.5 b) 10 c) 50 d) 25 e) 20

15 <u>.</u> F	ind the	small-signal	voltage gain of the	Q_2 stage, v_0/v_{g2} (in	V/V).
a) <mark>0.5</mark>	5 <mark>58</mark>	b) 0.641	c) 0.667	d) 0.717	e) 0.739

16. Assume in this question only that $R = 22 \text{ k}\Omega$. Find the small-signal voltage gain of the Q_1 stage, v_{g2}/v_i (in V/V). a) 22.0 b) 9.8 c) 13.9 d) 15.6 e) 19.7

17. Find the input resistance of the amplifier, R_{in} (in k Ω).a) 1.12b) 1.00c) 2.24d) 1.58e) 1.41

18. Find the	e output resistan	ce of the amplifie	er, R_{out} (in Ω).	
a) 1000	b) 791	c) 707	d) <mark>1581</mark>	e) 1118
19. Find the	e OCTC resistan	ce seen by C_{gs1} (in Ω).	
a) 883	b) 667	c) <mark>1056</mark>	d) 828	e) 717

Assume in the circuit shown below that $g_{\rm m} = 1.4 \text{ mA/V}$, $r_{\rm o} = 20 \text{ k}\Omega$, $R_{\rm sig} = 50 \text{ k}\Omega$, $R_{\rm L} = 48 \text{ k}\Omega$, $R_2 = 2 \text{ k}\Omega$, and $R_1 = 150 \text{ k}\Omega$. The current source is ideal.



20. Find the low-frequency small-signal voltage gain v_0/v_{sig} (in V/V). a) -9.22 b) -5.73 c) -8.00 d) -9.98 e) -11.39

21. Find the OCTC resistance seen by a capacitor connected between the output node and ground (in k Ω). a) 21.8 b) 29.7 c) 33.9 d) 41.5 e) 36.6

For the circuit shown below, the BJT has $r_0 = 25 \text{ k}\Omega$ and *very large* β . The resistor values are $R = 10 \text{ k}\Omega$, $R_2 = 1 \text{ k}\Omega$, $R_3 = 3 \text{ k}\Omega$, and $R_{\text{sig}} = 2 \text{ k}\Omega$. Assume $V_{\text{CC}} = 3 \text{ V}$. The two large capacitors shown are open-circuits at DC, but can be considered as short-circuits for all signal frequencies of interest, and during OCTC calculations.



24. Find the transconductance of the amplifier i_0/v_i (in mA/V). Assume that a load resistance $R_L = 5 \text{ k}\Omega$ is connected across the output. The current i_0 flows in the resistor R_L . a) 1.62 b) 3.23 c) 4.85 d) 6.46 e) 8.07

In the BJT amplifier circuit shown below, the device is biased using an ideal DC current source I = 2 mA, and has $\beta = 60$. The resistor values are: R = 60 k Ω , $R_1 = 100$ k Ω , $R_2 = 2.0$ k Ω , and $R_L = 50$ k Ω . The five capacitors shown are open-circuits at DC, but can be considered as short-circuits for all signal frequencies of interest.

